

Absolute maximum ratings

(Ta=25°C)

Symbol	Ratings	Unit
V _{DSS}	100	V
V _{GSS}	±20	V
I _D	±4	A
I _{D(pulse)}	±8 (PW≤1ms, duty≤1%)	A
E _{AS} *	15	mJ
P _T	5 (Ta=25°C, with all circuits operating, without heatsink)	W
	35 (Tc=25°C, with all circuits operating, with infinite heatsink)	
θ _{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ _{j-c}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
V _{ISO}	1000 (Between fin and lead pin, AC)	V _{rms}
T _{ch}	150	°C
T _{stg}	-40 to +150	°C

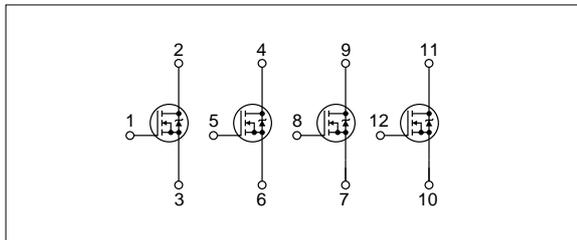
* : V_{DD}=20V, L=1mH, I_b=5A, unclamped, R_G=50Ω, see Fig. E on page 15.

Electrical characteristics

(Ta=25°C)

Symbol	Specification			Unit	Conditions
	min	typ	max		
V _{(BR)DSS}	100			V	I _D =250μA, V _{GS} =0V
I _{GSS}			±500	nA	V _{GS} =±20V
I _{DSS}			250	μA	V _{DS} =100V, V _{GS} =0V
V _{TH}	2.0		4.0	V	V _{DS} =10V, I _D =250μA
R _{e(yfs)}	1.0	1.5		S	V _{DS} =10V, I _D =2A
R _{DS(ON)}		0.5	0.6	Ω	V _{GS} =10V, I _D =2A
C _{iss}		180		pF	V _{DS} =25V, f=1.0MHz, V _{GS} =0V
C _{oss}		82		pF	
td(on)		15		ns	I _D =2A, V _{DD} ≐50V, R _L =25Ω, V _{GS} =10V, see Fig. 3 on page 16.
tr		20		ns	
td(off)		30		ns	
tf		10		ns	
V _{SD}		1.1	1.5	V	I _{SD} =4A, V _{GS} =0V
trr		250		ns	I _{SD} =±100mA

Equivalent circuit diagram



Characteristic curves